SP3004 Series 0.85pF Rail Clamp Array

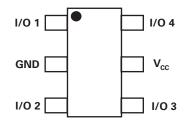




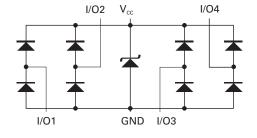
SP3004



Pinout



Functional Block Diagram



Description

The SP3004 has ultra low capacitance rail-to rail diodes with an additional zener diode fabricated in a proprietary silicon avalanche technology to protect each I/O pin providing a high level of protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes at the maximum level (Level 4) specified in the IEC 61000-4-2 international standard without performance degradation. Their very low loading capacitance also makes them ideal for protecting high speed signal pins such as HDMI, DVI, USB2.0, and IEEE 1394.

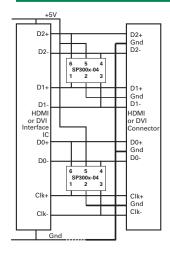
Features

- Low capacitance of 0.85pF (TYP) per I/O
- ESD protection of ±12kV contact discharge, ±15kV air discharge, (IEC61000-4-2)
- EFT protection, IEC61000-4-4, 40A (5/50ns)
- Low leakage current of 0.5µA (MAX) at 5V
- Small SOT563 package saves board space
- Lightning Protection, IEC61000-4-5, 4A (8/20µs)

Applications

- Computer Peripherals
- Mobile Phones
- PDA's
- Digital Cameras
- Network Hardware/Ports
- Test Equipment
- Medical Equipment

Application Example



A single 4 channel SP300x-04 device can be used to protect four of the data lines in a HDMI/DVI interface. Two (2) SP300x-04 devices provide protection for the main data lines. Low voltage ASIC HDMI/DVI drivers can also be protected with the SP300x-04, the $+V_{\rm CC}$ pins on the SP300x-04 can be substituted with a suitable bypass capacitor or in some backdrive applications the $+V_{\rm CC}$ of the SP300x-04 can be floated or NC.

Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

TVS Diode Arrays (SPA™ Family of Products)

Low Capacitance ESD Protection - SP3004 Series

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	4	А
T _{OP}	Operating Temperature	-40 to 85	°C
T _{STOR}	Storage Temperature	-50 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information

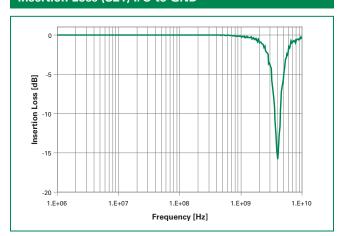
Parameter	Rating	Units
Storage Temperature Range	-65 to 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 10s)	260	°C

Electrical Characteristics (T_{OP}=25°C)

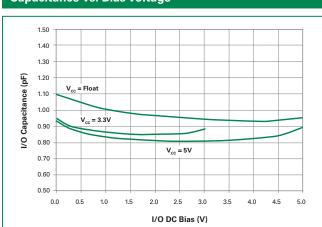
Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V _{RWM}	I _R ≤ 1μA			6	V
Reverse Leakage Current	I _{LEAK}	V _R =5V			0.5	μΑ
Clamp Voltage ¹	V _C	$I_{pp}=1A, t_p=8/20\mu s, Fwd$		10.0	12.0	V
Clairip Voltage	v c	I_{pp} =2A, t_p =8/20µs, Fwd		11.8	15.0	V
ESD Withstand Voltage ¹	\/	IEC61000-4-2 (Contact)	±12			kV
L3D Withstand Voltage	V _{ESD}	IEC61000-4-2 (Air)	±15			μA V V
Diode Capacitance ¹		Reverse Bias=0V	0.95	1.1	1.25	pF
Diode Capacitatice.	C _{I/O-GND}	Reverse Bias=1.65V	0.7	0.85	1	pF
Diode Capacitance ¹	C _{I/O-I/O}	Reverse Bias=0V		0.5		pF

Note: ¹ Parameter is guaranteed by design and/or device characterization.

Insertion Loss (S21) I/O to GND

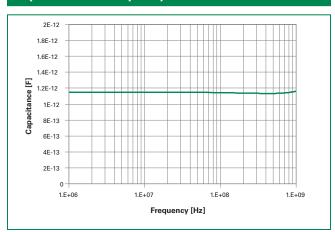


Capacitance vs. Bias Voltage





Capacitance vs. Frequency



Product Characteristics

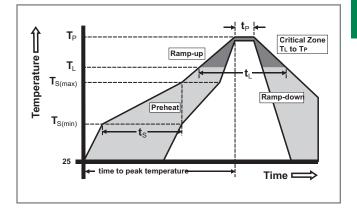
Lead Plating	Pre-Plated Frame	
Lead Material	Copper Alloy	
Lead Coplanarity	0.0004 inches (0.102mm)	
Subsitute Material	Silicon	
Body Material	Molded Epoxy	
Flammability	UL94-V-0	

- All dimensions are in millimeters
 Dimensions include solder plating.

- Dimensions include solder plating.
 Dimensions are exclusive of mold flash & metal burr.
 All specifications comply to JEDEC SPEC MO-223 Issue A
 Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
 Package surface matte finish VDI 11-13.

Soldering Parameters

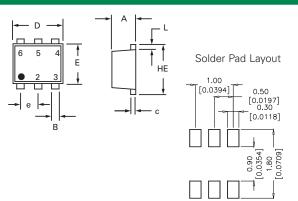
Reflow Condition		Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ramp up rate (Liquidus) Temp (T _L) to peak		3°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		3°C/second max	
Deflace	-Temperature (T _L) (Liquidus)	217°C	
Reflow	-Temperature (t _L)	60 – 150 seconds	
PeakTemp	perature (T _P)	250+0/-5 °C	
Time within 5°C of actual peak Temperature (t,)		20 - 40 seconds	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _P)		8 minutes Max.	
Do not exceed		260°C	





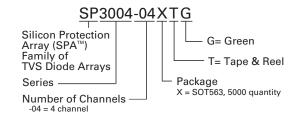
Low Capacitance ESD Protection - SP3004 Series

Package Dimensions — SOT563

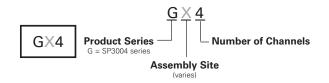


Package	SOT 563				
Pins	6				
	Millin	neters	Inches		
	Min Max		Min	Max	
Α	0.50	0.60	0.020	0.024	
В	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
E	1.10	1.30	0.043	0.051	
е	0.50 BSC		0.020 BSC		
L	0.10	0.30	0.004	0.012	
HE	1.50 1.70 0.059		0.067		

Part Numbering System



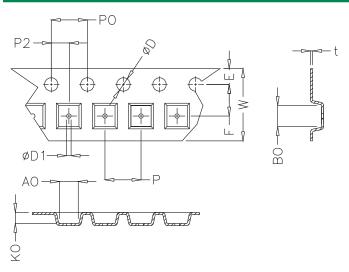
Part Marking System



Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SP3004-04XTG	SOT563	GX4	5000

Embossed Carrier Tape & Reel Specification — SOT563



	Millimetres		Incl	hes	
	Min	Max	Min	Max	
Е	1.65	1.85	0.065	0.073	
F	3.45	3.55	0.135	0.139	
P2	1.95	2.05	0.077	0.081	
D	1.40	1.60	0.055	0.063	
D1	0.45	0.55	0.017	0.021	
P0	3.90	4.10	0.154	0.161	
10P0	40.0+	/- 0.20	1.574+/-0.008		
W	7.70	8.10	0.303	0.318	
P	3.90	4.10	0.153	0.161	
A0	1.73	1.83	0.068	0.072	
В0	1.73	1.83	0.068	0.072	
K0	0.64	0.74	0.025	0.029	
t	0.22 max		0.009) max	